

Semistate and Circuits for Driver Neural Network Modules[†]
 Louiza Sellami and Robert W. Newcomb
 Microsystems Laboratory
 Electrical Engineering Department
 College Park, MD 20742 USA
 Phone: (301) 405-3662
 Fax: (301) 314-9281
 email: sellami@eng.umd.edu or newcomb@eng.umd.edu

Abstract:

The driver module is a primary one in the biologically realistic neural network program SYNETSIM. Here we introduce semistate equations for the driver module which are suitable for the transistorized electric circuits which we intend to realize from these equations.

I. Introduction

Among the various neural network programs available SYNETSIM [1] stands out as being the most biologically realistic that will run on IBM compatible PCs. Included in SYNETSIM are a number of modules which the user can insert to mimic various properties of neurons in neural networks. One of these modules is the DRIVER module which models the graded slow responses of some neuron membranes. In essence the driver module incorporates the slow opening and closing behavior of sodium and potassium channels. This modeling is done by allowing the effective conductances of associated channels in the driver module to vary according to laws, given below as Eqs. (1), determined by neurophysiologists. Here we interpret these laws in terms of a basic circuit, given in Fig. 1, with which we associate semistate equations, (2). From these latter we can set up a controlled source model, Fig. 2, which will lead to a transistorized version of the driver module (presently under development). Since the driver module is used in conjunction with other SYNETSIM modules, it can be considered to have an input and an output, and, hence, amenable to a semistate description useful for interconnections. However, because sometimes the membrane voltage is the input with the membrane current as output and sometimes the reverse, we develop two versions of semistate equations. Also we mention that because the nonlinearities are in the form of exponential conductances, these nonlinearities take some effort to properly realize with hardware.

II. The DRIVER Module Equations

In the driver module there are conductances for the main sodium and potassium channels, these two conductances being given by [2, eqs. (8.1, 8.2)]

$$G_i = \frac{\bar{G}_i}{1 + \exp[(V_{o1} - v_m(t) / \mu_i)} \quad i = Na, K \quad (1a)$$

where v_m is the membrane potential, and \bar{G}_i , V_{o1} and μ_i are constants associated with the basic sodium, $i=Na$, or potassium, $i=K$, channels

[physically \bar{G}_i is a channel conductance for infinite membrane potential, V_{o1} is a half-activation voltage and μ_i is a characteristic voltage for a channel]. Also to go with these conductances are the reversal potentials, $V_{Na} > 0$ and $V_K < 0$. In addition, in the driver module, there are two other time dependent channels associated with potassium with the conductances for these satisfying the differential equation

$$\tau_{K1} \dot{G}_{K1} = \frac{\bar{G}_{K1}}{1 + \exp[(V_{OK} - v_m(t) / \mu_K]} - G_{K1} \quad i=1,2 \quad (1b)$$

where the dot denotes differentiation with respect to time t and τ_{K1} and τ_{K2} are time constants for these two channels. Interpreting these equations in terms of batteries and resistors we directly obtain the circuit of Fig. 1 where the voltage dependent resistors are given by $R_i = 1/G_i$ for $i=Na, K, K1, K2$.

III. Semistate Equations

Canonical semistate equations are equations of the form [3]

$$\begin{aligned} \dot{x} &= A(x, t) + Bu & (2a) \\ y &= Cx & (2b) \end{aligned}$$

where x is the semistate vector, u is the input, y is the output, and E , B , C are constant matrices; A is a mapping which includes the nonlinearities and explicit time variations of the system which in the case of a linear time-invariant system is given in terms of a constant matrix A as $A \cdot x$. Our desire is to place the driver module equations into this form. Since there are many sets of possible semistate equations we wish to choose a set that is favorable to a realization by transistor circuits. For this we first convert Fig. 1 to Fig. 2 where we consider a conductance to be realized by a voltage controlled current source with the controlling (input) voltage being directly across (output) current source. With Fig. 2 in hand we proceed to set the semistate to be the s -vector (where superscript T denotes the transpose)

$$s^T = [v_{CK1}, v_{CK2}, i_{GNa}, i_{GK}, i_{GK1}, i_{GK2}, v_m, i_m] \quad (3)$$

To continue, we note that the choice of input and output depends upon how the driver module is to be used. In the usual cases either the membrane voltage is the input and the membrane current the output or vice versa. Thus, depending upon the input-output pairing there are two cases of interest while in either case the dynamics is the same. We have

[†] Supported in part by the US NSF Grant No. MIP 89-21122 and ONR Grant N00014-90-J-1114

References:

- [1]. D. K. Hartline, "Simulation of Restricted Neural Networks with Reprogrammable Neurons," IEEE Transactions on Circuits and Systems, Vol. 36, No. 5, May 1989, pp. 653 - 660.
- [2]. D. K. Hartline, "Synetsim 3.3 Users' Manual," Bekeney Laboratory, Honolulu, HI, 08/23/90.
- [3]. R. W. Newcomb and B. Dziurka, "Some Circuits and Systems Applications of Semistate Theory," Circuits Systems and Signal Processing, Vol 8, No. 3, 1989, ppl 235 - 260.
- [4]. R. L. Geiger, P. E. Allen, and N. R. Strader, "VLSI Design Techniques for Analog and Digital Circuits," McGraw-Hill Publishing Co., NY, 1990.

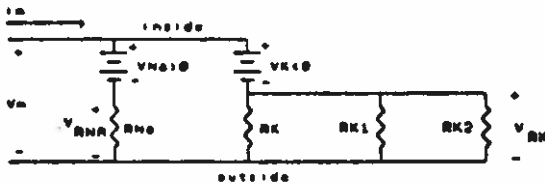


Figure 1
Circuit for Synetsim Equations

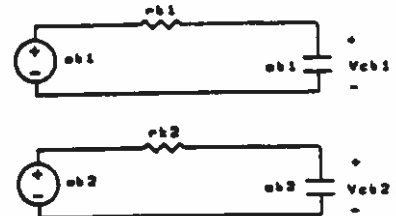
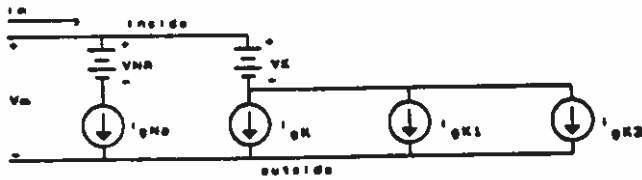


Figure 2
Equivalent for Semistate Equations

SINS '92

International Symposium on

IMPLICIT AND NONLINEAR SYSTEMS

14-15 December 1992

**Automation and Robotics Research Institute
The University of Texas at Arlington
Arlington, Texas**

General Chairmen

**F.L. Lewis
S.L. Campbell
E.W. Kamen**

International Program Committee

**C.T. Abdallah
M.A. Christodoulou
G. Conte
D.M. Dawson
D. Hinrichsen
L.R. Hunt
T. Kaczorek
N. Karcanias**

**M. Kocięcki
V. Kučera
A.J. Laub
M. Malabre
O.R. Mitchell
R.W. Newcomb
N.K. Nichols
D.H. Owens**

**K. Özçaldıran
M.K. Sain
I.W. Sandberg
G.N. Saridis
M. Šebek
J.M. Schumacher
V.L. Syrmos
K. Yeung
P. Zagalak**

Proceedings Editor

F.L. Lewis